# MSKSEMI















**ESD** 

TVS

TSS

MOV

GDT

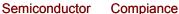
**PLED** 

# Broduct data sheet







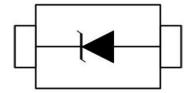






SOD-323

#### **PIN CONFIGURATION**



#### **FEATURES**

♦ Transient protection for high-speed data lines IEC 61000-4-2 (ESD) ±30kV (Contact) ±30kV (Air)

♦ Peak power dissipation: 1260W (8/20µs)

♦ Working voltages : 4.5V ♦ Low leakage current

♦ Low clamping voltage

♦ Solid-state silicon-avalanche technology

#### **MACHANICAL DATA**

♦ SOD-323 package

♦ Flammability Rating: UL 94V-0

♦ High temperature soldering guaranteed: 260°C/10s

♦ Packaging: Tape and Reel

♦ Reel size: 7 inch

#### **APPLICATIONS**

♦ Power lines

♦ Personal digital assistants (PDA's)

♦ Microprocessors based equipment

♦ Notebooks, Desktops, and Servers

♦ Cell phone Handsets and Accessories

♦ Portable Electronics

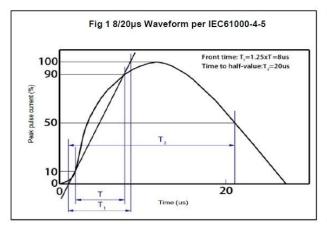
♦ Peripherals

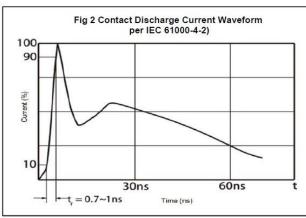
ABSOLUTE MAXIMUM RATING				
Symbol	Parameter	Value	Units	
V <sub>ESD</sub>	ESD per IEC 61000-4-2 (Contact) ESD per IEC 61000-4-2 (Air)	±30 ±30	kV	
P <sub>PP</sub>	Peak Pulse Power (8/20µs)	1260	W	
Ірр	Peak Pulse Current (8/20µs)	90	А	
T <sub>OPT</sub>	Operating Temperature	-55~125	°C	
T <sub>STG</sub>	Storage Temperature	-55~150	°C	
T∟	Lead Soldering Temperature	260(10sec)	°C	

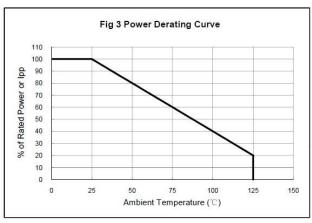


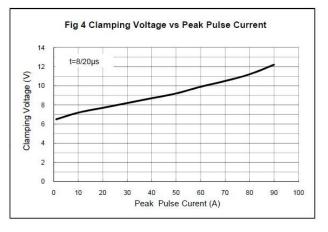
ELECTRICAL CHARACTERISTICS (Tamb=25°C)						
Symbol	Parameter	Test Condition	Min	Тур	Max	Units
$V_{RWM}$	Reverse Working Voltage				4.5	V
$V_{BR}$	Reverse Breakdown Voltage	I <sub>T</sub> = 1mA	5.0		7.0	V
$I_R$	Reverse Leakage Current	V <sub>RWM</sub> =4.5V			0.5	uA
Vc	Clamping Voltage	$I_{PP} = 10A, t_p = 8/20 \mu s$			9	V
		$I_{PP} = 90A, t_p = 8/20\mu s$			14	V
Сл	Junction Capacitance	V <sub>R</sub> = 0V, f = 1MHz			850	pF

#### **ELECTRICAL CHARACTERISTICS CURVE**







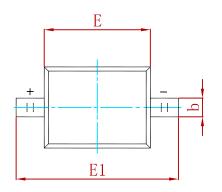


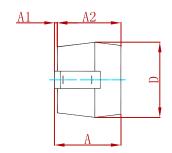


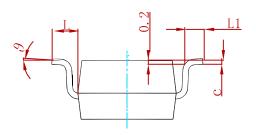
Semiconductor

Compiance

### PACKAGE MECHANICAL DATA

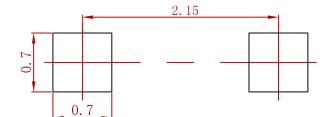






Cumbal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α		1.000		0.039	
A 1	0.000	0.100	0.000	0.004	
A2	0.800	0.900	0.031	0.035	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	1.200	1.400	0.047	0.055	
E	1.600	1.800	0.063	0.071	
E1	2.550	2.750	0.100	0.108	
L	0.475	REF.	0.019	REF.	
L1	0.250	0.400	0.010	0.016	
θ	0°	8°	0°	8°	

## **Suggested Pad Layout**



#### Note:

- 1. Controlling dimension: in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

#### **REEL SPECIFICATION**

P/N	PKG	QTY
PTVSHC3D5VU-MS	SOD-323	3000



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